



F100171

Triple 4-Input Multiplexer with Enable

General Description

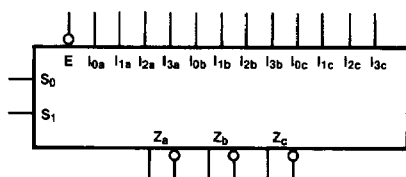
The F100171 contains three 4-input multiplexers which share a common decoder (inputs S_0 and S_1). Output buffer gates provide true and complement outputs. A HIGH on the Enable input ($\bar{E}$) forces all true outputs LOW (see Truth Table). All inputs have 50 k Ω pull-down resistors.

Refer to the F100371 datasheet for:

PCC packaging
Lower power
Military versions
Extended voltage specs ($-4.2V$ to $-5.7V$)

Ordering Code: See Section 8

Logic Symbol

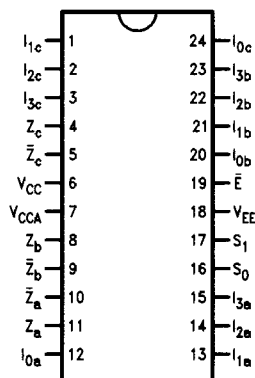


TL/F/9869-3

Pin Names	Description
$I_{0x}-I_{3x}$	Data Inputs
S_0, S_1	Select Inputs
$\bar{E}$	Enable Input (Active LOW)
Z_a-Z_c	Data Outputs
$\bar{Z}_a-\bar{Z}_c$	Complementary Data Outputs

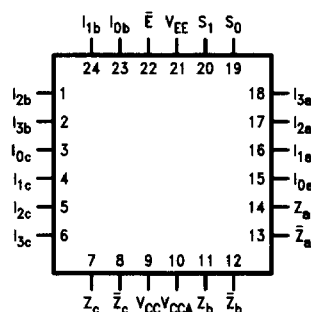
Connection Diagrams

24-Pin DIP



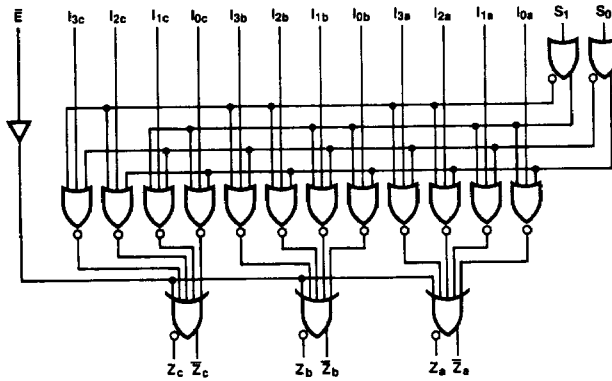
TL/F/9869-1

24-Pin Quad Cerpak



TL/F/9869-2

Logic Diagram



TL/F/9869-5

Truth Table

Inputs			Outputs
$\bar{E}$	S_0	S_1	Z_n
L	L	L	I_{0x}
L	H	L	I_{1x}
L	L	H	I_{2x}
L	H	H	I_{3x}
H	X	X	L

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

Absolute Maximum Ratings

Above which the useful life may be impaired. (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature -65°C to $+150^{\circ}\text{C}$
Maximum Junction Temperature (T_J) $+150^{\circ}\text{C}$

Case Temperature under Bias (T_C) 0°C to $+85^{\circ}\text{C}$
 V_{EE} Pin Potential to Ground Pin -7.0V to $+0.5\text{V}$
Input Voltage (DC) V_{EE} to $+0.5\text{V}$
Output Current (DC Output HIGH) -50mA
Operating Range (Note 2) -5.7V to -4.2V

DC Electrical Characteristics

$V_{EE} = -4.5\text{V}$, $V_{CC} = V_{CCA} = \text{GND}$, $T_C = 0^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ (Note 3)

Symbol	Parameter	Min	Typ	Max	Units	Conditions (Note 4)	
V _{OH}	Output HIGH Voltage	−1025	−955	−880	mV	V _{IN} = V _{IH} (Max) or V _{IL} (Min)	Loading with 50Ω to −2.0V
V _{OL}	Output LOW Voltage	−1810	−1705	−1620			
V _{OHC}	Output HIGH Voltage	−1035			mV	V _{IN} = V _{IH} (Min) or V _{IL} (Max)	Loading with 50Ω to −2.0V
V _{OLC}	Output LOW Voltage			−1610			
V _{IH}	Input HIGH Voltage	−1165		−880	mV	Guaranteed HIGH Signal for All Inputs	
V _{IL}	Input LOW Voltage	−1810		−1475	mV	Guaranteed LOW Signal for All Inputs	
I _{IL}	Input LOW Current	0.50			μA	V _{IN} = V _{IL} (Min)	

DC Electrical Characteristics

$V_{EE} = -4.2\text{V}$, $V_{CC} = V_{CCA} = \text{GND}$, $T_C = 0^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ (Note 3)

Symbol	Parameter	Min	Typ	Max	Units	Conditions (Note 4)	
V _{OH}	Output HIGH Voltage	−1020		−870	mV	V _{IN} = V _{IH} (Max) or V _{IL} (Min)	Loading with 50Ω to −2.0V
V _{OL}	Output LOW Voltage	−1810		−1605			
V _{OHC}	Output HIGH Voltage	−1030			mV	V _{IN} = V _{IH} (Min) or V _{IL} (Max)	Loading with 50Ω to −2.0V
V _{OLC}	Output LOW Voltage			−1595			
V _{IH}	Input HIGH Voltage	−1150		−870	mV	Guaranteed HIGH Signal for All Inputs	
V _{IL}	Input LOW Voltage	−1810		−1475	mV	Guaranteed LOW Signal for All Inputs	
I _{IL}	Input LOW Current	0.50			μA	V _{IN} = V _{IL} (Min)	

DC Electrical Characteristics

$V_{EE} = -4.8\text{V}$, $V_{CC} = V_{CCA} = \text{GND}$, $T_C = 0^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ (Note 3)

Symbol	Parameter	Min	Typ	Max	Units	Conditions (Note 4)	
V _{OH}	Output HIGH Voltage	−1035		−880	mV	V _{IN} = V _{IH} (Max) or V _{IL} (Min)	Loading with 50Ω to −2.0V
V _{OL}	Output LOW Voltage	−1830		−1620			
V _{OHC}	Output HIGH Voltage	−1045			mV	V _{IN} = V _{IH} (Min) or V _{IL} (Max)	Loading with 50Ω to −2.0V
V _{OLC}	Output LOW Voltage			−1610			
V _{IH}	Input HIGH Voltage	−1165		−880	mV	Guaranteed HIGH Signal for All Inputs	
V _{IL}	Input LOW Voltage	−1830		−1490	mV	Guaranteed LOW Signal for All Inputs	
I _{IL}	Input LOW Current	0.50			μA	V _{IN} = V _{IL} (Min)	

Note 1: Absolute maximum ratings are those values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Parametric values specified at -4.2V to -4.8V .

Note 3: The specified limits represent the "worst case" value for the parameter. Since these "worst case" values normally occur at the temperature extremes, additional noise immunity and guard banding can be achieved by decreasing the allowable system operating ranges.

Note 4: Conditions for testing shown in the tables are chosen to guarantee operation under "worst case" conditions.

DC Electrical Characteristics
 $V_{EE} = -4.2V$ to $-4.8V$ unless otherwise specified, $V_{CC} = V_{CCA} = GND$, $T_C = 0^\circ C$ to $+85^\circ C$

Symbol	Parameter	Min	Typ	Max	Units	Conditions
I_{IH}	Input HIGH Current $I_{Ox}-I_{3x}$ $S_0, S_1, \bar{E}$			340 300	μA	$V_{IN} = V_{IH(max)}$
I_{EE}	Power Supply Current	-114	-80	-56	mA	Inputs Open

Ceramic Dual-In-Line Package AC Electrical Characteristics
 $V_{EE} = -4.2V$ to $-4.8V$, $V_{CC} = V_{CCA} = GND$

Symbol	Parameter	$T_C = 0^\circ C$		$T_C = +25^\circ C$		$T_C = +85^\circ C$		Units	Conditions
		Min	Max	Min	Max	Min	Max		
t_{PLH} t_{PHL}	Propagation Delay $I_{Ox}-I_{3x}$ to Output	0.45	1.70	0.45	1.60	0.50	1.70	ns	Figures 1 and 2
t_{PLH} t_{PHL}	Propagation Delay S_0, S_1 to Output	0.90	2.40	0.90	2.60	1.00	3.00	ns	
t_{PLH} t_{PHL}	Propagation Delay $\bar{E}$ to Output	0.65	2.40	0.65	2.30	0.75	2.40	ns	
t_{TLH} t_{THL}	Transition Time 20% to 80%, 80% to 20%	0.45	1.80	0.45	1.60	0.45	1.60	ns	

Cerpak AC Electrical Characteristics
 $V_{EE} = -4.2V$ to $-4.8V$, $V_{CC} = V_{CCA} = GND$

Symbol	Parameter	$T_C = 0^\circ C$		$T_C = +25^\circ C$		$T_C = +85^\circ C$		Units	Conditions
		Min	Max	Min	Max	Min	Max		
t_{PLH} t_{PHL}	Propagation Delay $I_{Ox}-I_{3x}$ to Output	0.45	1.50	0.45	1.40	0.50	1.50	ns	Figures 1 and 2
t_{PLH} t_{PHL}	Propagation Delay S_0, S_1 to Output	0.90	2.20	0.90	2.40	1.00	2.80	ns	
t_{PLH} t_{PHL}	Propagation Delay $\bar{E}$ to Output	0.65	2.20	0.65	2.10	0.75	2.20	ns	
t_{TLH} t_{THL}	Transition Time 20% to 80%, 80% to 20%	0.45	1.70	0.45	1.50	0.45	1.50	ns	

